



DMN2024U

Product Summary

V _{(BR)DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
	$25m\Omega @ V_{GS} = 4.5V$	6.8A
20V	$29 \mathrm{m}\Omega @ \mathrm{V}_{\mathrm{GS}} = 2.5 \mathrm{V}$	5.5A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, which make it ideal for high-efficiency power management applications.

- Backlighting
- Power-Management Functions
- DC-DC Converters
- Motor Control





Top View

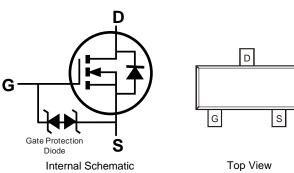
N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low-Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (e3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2024U-7	SOT23	3000/Tape & Reel
DMN2024U-13	SOT23	10,000/Tape & Reel

Notes:

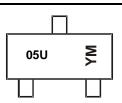
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



05U = Product Type Marking CodeYM = Date Code Marking $Y or <math>\overline{Y}$ = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Year	2018		2019	2020		2021	2022		2023	2024		2025
Code	F		G	Н		1	J		К	L		М
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Νον	Dec
Code	4	2	2	4	Б	6	7	0	0	0	N	Р



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Drain-Source Voltage		V _{DSS}	20	V
Gate-Source Voltage		V _{GSS}	±10	V
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$ State State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		ID	6.8 5.5	А
Maximum Continuous Body Diode Forward Curre	ent (Note 6)	ls	2.2	А
Pulsed Drain Current (10µs pulse, duty cycle = 11	%)	I _{DM}	45	А

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)		PD	0.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{OJA}	159	°C/W
Total Power Dissipation (Note 6)		PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{OJA}	92	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	20	—		V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current T _J = +25°C	IDSS	—	—	1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	—		±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)					-	
Gate Threshold Voltage	V _{GS(TH)}	0.5	-	0.9	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
			16	25		$V_{GS} = 4.5V, I_D = 6.5A$
Static Drain-Source On-Resistance	R _{DS(ON)}	—	18.5	29	mΩ	$V_{GS} = 2.5V, I_D = 5.5A$
			23	36		$V_{GS} = 1.8V, I_D = 3.5A$
Diode Forward Voltage	V _{SD}	—	0.8	1.2	V	$V_{GS} = 0V, I_D = 5A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	647		pF	
Output Capacitance	Coss	—	78	_	pF	V _{DS} = 10V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	38		pF	
Gate Resistance	Rg	—	628	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg	—	7.1	—	nC	
Gate-Source Charge	Q _{gs}	—	0.9	—	nC	$V_{GS} = 4.5V, V_{DS} = 10V, I_D = 6.5A$
Gate-Drain Charge	Q _{gd}	_	0.7		nC	
Turn-On Delay Time	t _{D(ON)}	—	98	_	ns	
Turn-On Rise Time	t _R	—	140	_	ns	$V_{DS} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t _{D(OFF)}	—	1024	_	ns	$R_L = 10\Omega, \ R_G = 6\Omega, \ I_D = 1A$
Turn-Off Fall Time	t _F	—	434	—	ns	
Reverse Recovery Time	t _{RR}	_	245	—	ns	I _F = 1.0A, di/dt = 100A/µs
Reverse Recovery Charge	Q _{RR}	_	149	—	nC	I _F = 1.0A, di/dt = 100A/µs

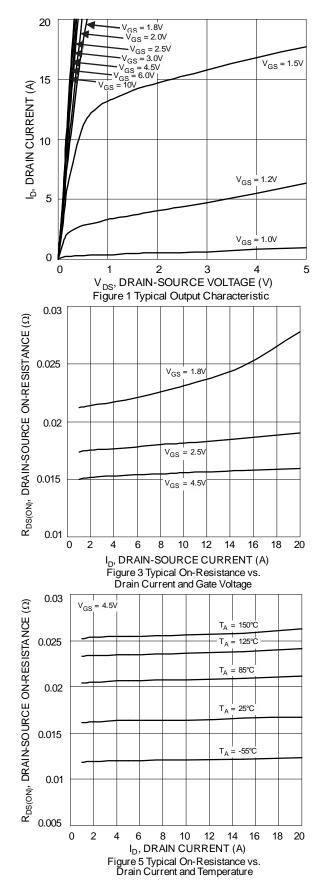
Notes:

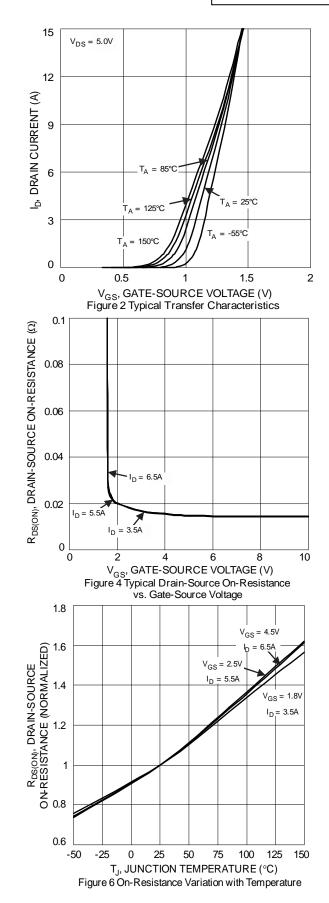
Device mounted on FR-4 PCB with minimum recommended pad layout.
 Device mounted on 1" x 1" FR-4 PCB with high-coverage 2oz copper, single sided.

7. Short duration pulse test used to minimize self-heating effect.

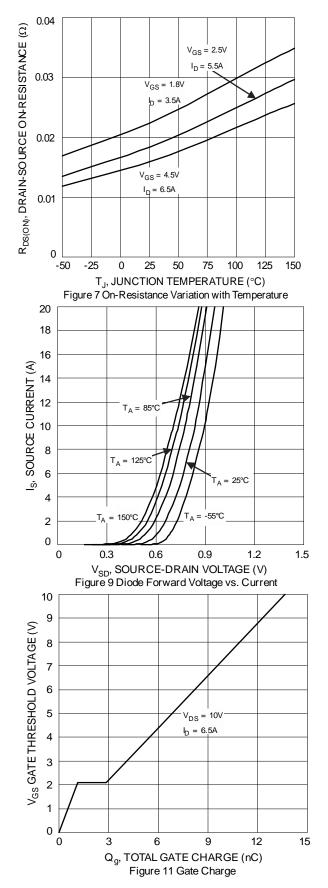
8. Guaranteed by design. Not subject to product testing.

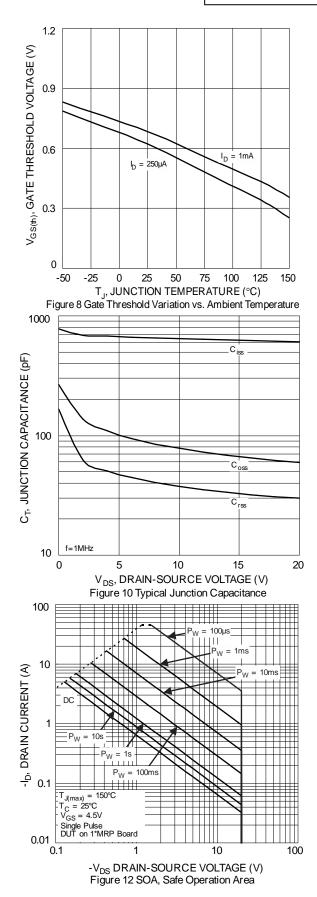




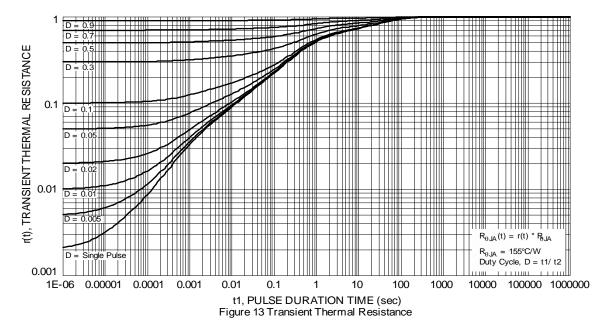








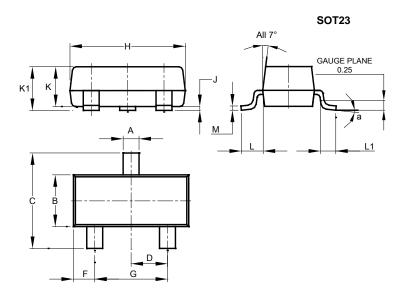






Package Outline Dimensions

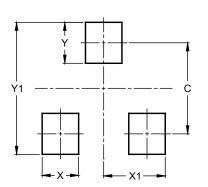
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23								
Dim	Min	Max	Тур						
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
Н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
K	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	0°	8°							
All	Dimens	ions in	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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